

**FULLY DECODED 8,192 BIT MASK
PROGRAMMABLE READ ONLY MEMORY**

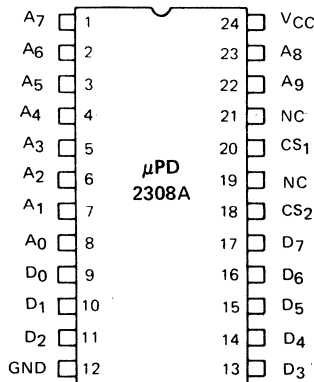
DESCRIPTION The NEC μPD2308A is a high-speed 8,192-bit mask-programmable Read Only Memory organized as 1024 words by 8 bits. The μPD2308A is fabricated with N-channel MOS technology.

The inputs and outputs are fully TTL-compatible. The device operates with a single +5V power supply. The three chip select inputs are programmable. Any combination of active high or low level chip select inputs can be defined and desired chip select code is fixed during the masking process.

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- FEATURES**
- Access Time 450 ns Max
 - 1024 Words x 8 Bits Organization
 - Single +5V ±10% Power Supply Voltage
 - Directly TTL-Compatible – All Inputs and Outputs
 - Two Programmable Chip Select Inputs for Easy Memory Expansion
 - Three-State Output – OR-Tie Capability
 - On-Chip Address Fully Decoded
 - All Inputs Protected Against Static Charge
 - Direct Replacement for 2308A
 - Available in 24-pin-plastic or ceramic packages

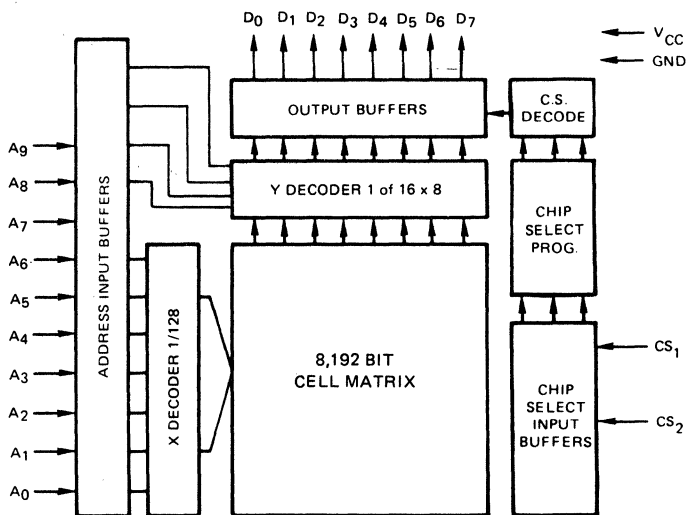
PIN CONFIGURATION



PIN NAMES

A ₀ – A ₉	Address Inputs
D ₀ – D ₇	Data Outputs
CS ₁ – CS ₂	Programmable Chip Select Inputs

μ PD2308A



BLOCK DIAGRAM

Operating Temperature -10°C to +70°C
 Storage Temperature -65°C to +125°C
 Voltage on Any Pin -0.5 to +7.0 Volts ①

ABSOLUTE MAXIMUM RATINGS*

Note: ① With Respect to Ground.

COMMENT: Stress above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

*T_a = 25°C

T_a = -10°C to +70°C; V_{CC} = +5 ± 5% unless otherwise noted.

DC CHARACTERISTICS

PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP ①	MAX		
Input Load Current (All Input Pins)	I _{LI}			+10	μA	V _{IN} = V _{CC}
				-10	μA	V _{IN} = 0V
Output Leakage Current	I _{LOH}			+10	μA	Chip Deselected, V _O = V _{CC}
Power Supply Current	I _{CC}		60	85	mA	
Input "Low" Voltage	V _{IL}	-0.5		0.8	V	
Input "High" Voltage	V _{IH}	2.0		V _{CC}	V	
Output "Low" Voltage	V _{OL}			0.4	V	I _{OL} = 3.2 mA
Output "High" Voltage	V _{OH}	+2.4			V	I _{OH} = -200 μA

Note: ① Typical values for T_a = 25°C and nominal supply voltage.

CAPACITANCE

$T_a = 25^\circ\text{C}; f = 1\text{ MHz}$

PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP	MAX		
Input Capacitance	C _{IN}		5	7	pf	All Pins Except Pin Under Test Tied to AC Ground
Output Capacitance	C _{OUT}		7	10	pf	All Pins Except Pin Under Test Tied to AC Ground

AC CHARACTERISTICS

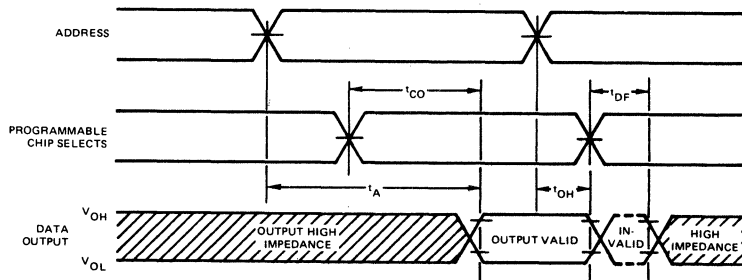
$T_a = -10^\circ\text{C to } +70^\circ\text{C}; V_{CC} = +5\text{V} \pm 5\%$ unless otherwise specified.

PARAMETER	SYMBOL	LIMITS			UNIT	TEST CONDITIONS
		MIN	TYP ^①	MAX		
Address to Output Delay Time	t _A		350	450	ns	t _T = t _r = t _f = 20 ns V _{ref in} = 1V, 2.2V V _{ref out} = 0.8V, 2V Output LOAD = 1 TTL GATE C _L = 100 pf
Chip Select to Output Enable Delay Time	t _{CO}			120	ns	
Chip Deselect to Output Data Float Delay Time	t _{DF}	10		100	ns	
Previous Data Valid After Address Change	t _{OH}	20			ns	

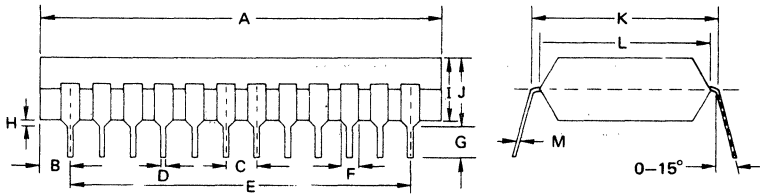
Note: ① $T_a = 25^\circ\text{C}; V_{CC} = +5\text{V}$



TIMING WAVEFORMS



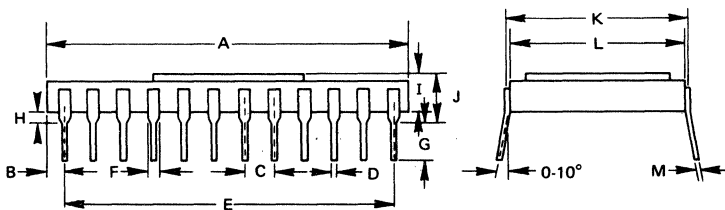
μPD2308A



PACKAGE OUTLINES
μPD2308AC

Plastic

ITEM	MILLIMETERS	INCHES
A	33 MAX	1.3 MAX
B	2.53	0.1
C	2.54	0.1
D	0.5 ± 0.1	0.02 ± 0.004
E	27.94	1.1
F	1.5	0.059
G	2.54 MIN	0.1 MIN
H	0.5 MIN	0.02 MIN
I	5.22 MAX	0.205 MAX
J	5.72 MAX	0.225 MAX
K	15.24	0.6
L	13.2	0.55 MAX
M	0.25 ^{+0.10} _{-0.05}	0.01 ^{+0.004} _{-0.0019}



μPD2308AD

Ceramic

ITEM	MILLIMETERS	INCHES
A	30.78 MAX.	1.23 MAX.
B	1.53 MAX.	0.07 MAX.
C	2.54 ± 0.1	0.10 ± 0.004
D	0.46 ± 0.8	0.018 ± 0.03
E	27.94 ± 0.1	1.10 ± 0.004
F	1.02 MIN.	0.04 MIN.
G	3.2 MIN.	0.125 MIN.
H	1.02 MIN.	0.04 MIN.
I	3.23 MAX.	0.13 MAX.
J	4.25 MAX.	0.17 MAX.
K	15.24 TYP.	0.60 TYP.
L	14.93 TYP.	0.59 TYP.
M	0.25 ± 0.05	0.010 ± 0.002